

	Type	Hits	Search Text	DBs	Time Stamp
1	IS&R	1	("5523700").PN.	USPAT	2002/03/19 14:21
2	BRS	1	"5523700" and dop\$3 and electron	USPAT	2002/03/19 14:57
3	BRS	1	"5523700" and dop\$3 and semiconductor and (transmission ADJ electron ADJ microscopy or TEM) and (atomic ADJ force ADJ microscopy or AFM)	USPAT	2002/03/19 15:16
4	BRS	1	"6320655"	USPAT	2002/03/19 17:37
5	BRS	1	"6028664".PN.	USPAT	2002/03/19 17:37
6	BRS	1	"5917588".PN.	USPAT	2002/03/19 17:38
7	BRS	1	"5877035".PN.	USPAT	2002/03/19 17:38
8	BRS	1	"5847821".PN.	USPAT	2002/03/19 17:41
9	BRS	1	"5847821".PN.	USPAT	2002/03/19 17:41
10	BRS	1	"5267017".PN.	USPAT	2002/03/19 17:41
11	BRS	1	"5877035".PN.	USPAT	2002/03/19 17:41
12	BRS	1	dop\$3 and semiconductor and (transmission ADJ electron ADJ microscopy or TEM) and (atomic ADJ force ADJ microscopy or AFM) and image and lens	USPAT	2002/03/19 17:46
13	BRS	2	"5523700" and dop\$3 and semiconductor and (atomic ADJ force ADJ microscopy or AFM)	USPAT	2002/03/19 15:39
14	BRS	2	dop\$3 with concentration with two adj dimension\$3 and (transmission ADJ electron ADJ microscopy or TEM) and (atomic ADJ force ADJ microscopy or AFM)	USPAT	2002/03/19 15:58
15	BRS	3	("5523700" and dop\$3) and dimension	USPAT	2002/03/19 15:12
16	BRS	3	dop\$3 and semiconductor and TEM with phase and two adj dimension\$3	USPAT	2002/03/19 15:37

	Type	Hits	Search Text	DBs	Time Stamp
17	BRS	3	dop\$3 and semiconductor and (transmission ADJ electron ADJ microscopy or TEM) and (atomic ADJ force ADJ microscopy or AFM) and camera	USPAT	2002/03/19 17:45
18	BRS	3	324/765.ccls. and semiconductor and dop\$4 adj thickness	USPAT	2002/03/19 18:26
19	BRS	4	"5523700" and dop\$3	USPAT	2002/03/19 18:01
20	BRS	4	("5523700" and dop\$3) and dimension\$3	USPAT	2002/03/19 15:13
21	BRS	4	("5523700" and dop\$3) and two-dimension\$3	USPAT	2002/03/19 15:13
22	BRS	4	"5523700" and dop\$3 and semiconductor and two adj dimension\$3	USPAT	2002/03/19 15:40
23	BRS	4	"5523700" and dop\$3 and two adj dimension\$3	USPAT	2002/03/19 18:02
24	BRS	4	(324/765.ccls. 324/751-753.ccls.) and dop\$4 with concentration and (laser or light) and Fourier	USPAT	2002/03/20 14:21
25	BRS	4	(324/765.ccls. 324/751-753.ccls.) and dop\$4 same concentration and (laser or light) and Fourier	USPAT	2002/03/20 14:33
26	BRS	4	(324/765.ccls. 324/751-753.ccls.) and dop\$4 and concentration and (laser or light) and Fourier	USPAT	2002/03/20 14:33
27	BRS	6	"5523700"	USPAT	2002/03/19 15:11
28	BRS	6	dop\$3 and (transmission ADJ electron ADJ microscopy or TEM) and (atomic ADJ force ADJ microscopy or AFM) and two adj dimension\$3 and electron adj beam	USPAT	2002/03/19 16:39
29	BRS	7	dop\$3 and two adj dimens\$4 and semiconductor and (transmission ADJ electron ADJ microscopy or TEM) and image	USPAT	2002/03/19 18:08

	Type	Hits	Search Text	DBs	Time Stamp
30	BRS	8	dop\$3 and semiconductor and (transmission ADJ electron ADJ microscopy or TEM) and (atomic ADJ force ADJ microscopy or AFM) and two adj dimension\$3 and phase	USPAT	2002/03/19 15:34
31	BRS	9	dop\$3 and concentration and two adj dimens\$4 and semiconductor and (transmission ADJ electron ADJ microscopy or TEM)	USPAT	2002/03/19 17:58
32	BRS	12	dop\$3 and semiconductor and (transmission ADJ electron ADJ microscopy or TEM) and (atomic ADJ force ADJ microscopy or AFM) and two-dimension\$3	USPAT	2002/03/19 15:19
33	BRS	12	dop\$3 with concentration and semiconductor and TEM and two adj dimension\$3 and imag\$4	USPAT	2002/03/19 16:07
34	BRS	12	(( "324/501").CCLS.) and semiconductor and dop\$4	USPAT	2002/03/19 18:25
35	BRS	15	dop\$3 and semiconductor and (transmission ADJ electron ADJ microscopy or TEM) and (atomic ADJ force ADJ microscopy or AFM) and two adj dimension\$3	USPAT	2002/03/19 15:19
36	BRS	15	dop\$3 and semiconductor and TEM and AFM and two adj dimension\$3	USPAT	2002/03/19 15:35
37	BRS	16	324/765.ccls. and semiconductor and dop\$4 with concentration and laser	USPAT	2002/03/19 18:39
38	BRS	16	324/765.ccls. and dop\$4 with concentration and laser	USPAT	2002/03/20 13:57
39	BRS	17	dop\$3 and semiconductor and (transmission ADJ electron ADJ microscopy or TEM) and (atomic ADJ force ADJ microscopy or AFM) and two adj dimension\$3	USPAT	2002/03/19 15:50

	Type	Hits	Search Text	DBs	Time Stamp
40	BRS	18	dop\$3 and semiconductor and (transmission ADJ electron ADJ microscopy or TEM) and image and lens and camera	USPAT	2002/03/19 17:48
41	BRS	27	dop\$3 and (transmission ADJ electron ADJ microscopy or TEM) and (atomic ADJ force ADJ microscopy or AFM) and two adj dimension\$3	USPAT	2002/03/19 16:38
42	BRS	27	(324/765.ccls. 324/751-753.ccls.) and dop\$4 with concentration and laser	USPAT	2002/03/20 14:09
43	BRS	46	324/765.ccls. and semiconductor and dop\$4 with concentration	USPAT	2002/03/19 18:29
44	BRS	49	dop\$3 same semiconductor and TEM and image and electron adj beam	USPAT	2002/03/19 18:11
45	BRS	49	dop\$3 same semiconductor and TEM and image and electron adj beam	USPAT	2002/03/19 18:16
46	BRS	50	dop\$3 and semiconductor and (transmission ADJ electron ADJ microscopy or TEM) and image and lens	USPAT	2002/03/19 17:52
47	BRS	51	dop\$3 and semiconductor and TEM and two adj dimension\$3 and imag\$4	USPAT	2002/03/19 16:06
48	BRS	58	dop\$3 and semiconductor and (transmission ADJ electron ADJ microscopy or TEM) and (atomic ADJ force ADJ microscopy or AFM)	USPAT	2002/03/19 17:42
49	BRS	58	((("324/501").CCLS.) and semiconductor	USPAT	2002/03/19 18:17
50	BRS	94	dop\$3 and semiconductor and TEM and two adj dimension\$3	USPAT	2002/03/19 16:04
51	BRS	144	dop\$3 and TEM and image and electron adj beam	USPAT	2002/03/19 18:10
52	IS&R	154	("324/501").CCLS.	USPAT	2002/03/19 18:17
53	BRS	182	324/765.ccls. and semiconductor and dop\$4	USPAT	2002/03/19 18:25

	Type	Hits	Search Text	DBs	Time Stamp
54	BRS	364	dop\$3 and semiconductor and (transmission ADJ electron ADJ microscopy or TEM) and image	USPAT	2002/03/19 17:53
55	BRS	512	dop\$3 and TEM and image	USPAT	2002/03/19 18:10
56	BRS	99816	dop\$3 TEM and planar ADJ electron ADJ wave and image	USPAT	2002/03/19 18:09
57	BRS	18131 4	324/765.ccls. and semiconductor and dop\$4 with concentration snd laser	USPAT	2002/03/19 18:29